

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	38	(finFET fin adj transistor) with (channel near3 top)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:41
L2	41	(finFET fin adj3 transistor) AND 257/347-349,314-318,365-368.CCLS. AND 438/157,257-257,281-283.CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:41
L3	15	(finFET fin adj transistor) near3 (channel) with tri adj gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:42
L5	1	(transistor with stack with silicon with insulator adj layer with plurality near3 channels and silicon adj oxide near3 insulation adj layer with dielectric adj layer near3 silicon adj oxide and gate adj electrode and gate adj configuration with different with remaining adj channels).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:46
L6	41	(finFET fin adj3 transistor) AND 257/347-349,314-318,365-368.CCLS. AND 438/157,257-257,281-283.CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:47
L7	436	(finFET fin adj transistor).ti.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/04/08 08:48

S1	1	10/711200	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 07:39
S2	10	("5940716"   "5981356"   "6080637"   "6093621"   "6583060").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 07:40
S3	80	("5940716"   "5981356"   "6080637"   "6093621"   "6583060")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 07:47
S4	49	S3 and transistor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 07:49
S6	327	(finFET fin adj transistor) near3 (channel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 14:41
S7	327	(finFET fin adj transistor) near3 (channel)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:13
S8	458	(finFET fin adj3 transistor).TI.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 12:44
S10	14078	257/347-349,314- 318,365-368.CCLS. OR 438/157,257-257,281- 283.CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 12:45

S11	307	(finFET fin adj3 transistor) AND S10	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 14:12
S12	6	"6531246"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/01/03 14:12
S13	8	(finFET fin adj transistor) near3 (channel near3 plurality)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 12:56
S14	3	2005/0098822	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/06 14:42
S15	7	("20030042531"   "20030151077"   "20030178670"   "20050098822"   "6118161"   "6635923"   "6660596").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/06/06 14:42
S16	411	(finFET fin adj transistor) near3 (channel) with channel	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:20
S17	12	(finFET fin adj transistor) near3 (channel) with tri adj gate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:14
S18	0	(finFET fin adj transistor) near3 (channel near top)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:21

S19	22	(finFET fin adj transistor) with (channel near3 top)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/12 10:21
S20	6	("20050029603"   "6162368"   "6350693"   "6431959"   "6458662"   "6855607").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/10/18 17:19

4/ 8/ 2008 8:57:22 AM

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